

COMPLIANT



# Low-Voltage, Low R<sub>ON</sub>, Single Analog Switch In miniQFN-6 Package

### **DESCRIPTION**

The DG2511, DG2512, DG2513 are low on-resistance, single-pole/double-throw or single-pole/single-throw monolithic CMOS analog switch. It is designed for low voltage applications. The DG2511, DG2512, DG2513 are ideal for portable and battery powered equipment, requiring high performance and efficient use of board space. In additional to the low on-resistance (1.3  $\Omega$  at 2.7 V).

The DG2511 is an SPDT and the DG2512, DG2513 are SPST. The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

The DG2511, DG2512, DG2513 are built on Vishay Siliconix's low voltage JI5L process. An epitaxial layer prevents latchup.

Break-before-make is guaranteed.

The DG2511, DG2512, DG2513 represents a breakthrough in packaging development for analog switching products. The miniQFN-6 package (1.2 x 1 mm).

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with NiPdAu device terminations, the lead (Pb)-free "-E4" suffix is being used as a designator.

### **FEATURES**

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance  $R_{ON}$ : 1.3  $\Omega$  at 2.7 V
- Low charge injection
- Latch-up current > 300 mA (JESD78A)
- miniQFN-6 package (1.2 x 1 mm)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

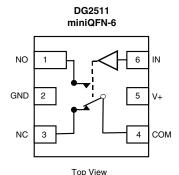
### BENEFITS

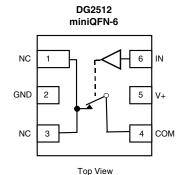
- Reduced power consumption
- Simple logic interface
- High accuracy
- Reduce board space
- Guaranteed 2 V operation

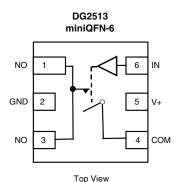
### **APPLICATIONS**

- Cellular phones
- Communication systems
- Portable test equipment
- Battery operated systems
- Sample and hold circuits
- ADC and DAC applications
- Low voltage data acquisition systems

### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**







Ax

Device Marking: Ax for DG2511 Bx for DG2512 Cx for DG2513 x = Date/Lot Traceability Code

Note: Pin 1 has long lead

TRUTH TABLE						
Logic	NC	NO				
0	On	Off				
1	Off	On				

COMMERCIAL ORDERING INFORMATION						
Temp Range	Package	Part Number				
	miniQFN-6	DG2511DN-T1-E4				
- 40 °C to 85 °C	Lead (Pb)-free	DG2512DN-T1-E4 DG2513DN-T1-E4				
	with Tape and Reel	DG2513DN-11-E4				

# DG2511, DG2512, DG2513

# Vishay Siliconix



ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Reference V+ to GND		- 0.3 to + 6	V			
IN, COM, NC, NO <sup>a</sup>		- 0.3 to (V+ + 0.3)				
Continuous Current (NO, NC, COM pins)		± 150	mA			
Peak Current (Pulsed at 1 ms, 10 % duty cy	cle)	± 300	IIIA			
Storage Temperature D Suffix		- 65 to 150	°C			
Power Dissipation (Packages) <sup>b</sup>	miniQFN-6 <sup>c</sup>	160	mW			

### Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 2 mW/°C above 70 °C.

SPECIFICATIONS (V+	= 3 V)						
		Test Conditions		Limits - 40 °C to 85 °C			
_		Otherwise Unless Specified					
Parameter	Symbol	V+ = 3 V, ± 10 %,V <sub>IN</sub> = 0.4 V or 2 V <sup>e</sup>	Temp. <sup>a</sup>	Min.b	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit
Analog Switch			1	T		,	
Analog Signal Range <sup>d</sup>	V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>		Full	0		V+	٧
On-Resistance	R <sub>ON</sub>	V+ = 2.7 V, V <sub>COM</sub> = 0.5 V/1.5 V	Room Full		1.4	1.7 1.9	
R <sub>ON</sub> Match	$\Delta R_{ON}$	$I_{NO}$ , $I_{NC} = 100 \text{ mA}$	Room			0.15	Ω
R <sub>ON</sub> Flatness	R <sub>ON</sub> Flatness	INO, INC = 100 IIIA	Room		0.3	0.4	
Outlet Off Leaders Outlet	I <sub>NO(off)</sub>	V+ = 3.3 V,	Room Full	- 2 - 20		2 20	nA
Switch Off Leakage Current <sup>f</sup>	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC}$ = 1 V/3 V, $V_{COM}$ = 3 V/1 V	Room Full	- 2 - 20		2 20	
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V/3 V}$	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.6			V
Input Low Voltage	V <sub>INL</sub>		Full			0.4	ľ
Input Capacitance	C <sub>in</sub>		Full		4		pF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0$ or $V+$	Full	1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{NO} \text{ or } V_{NC} = 1.5 \text{ V},$	Room Full		18	43 49	
Turn-Off Time	t <sub>OFF</sub>	$R_L = 50 \Omega$ , $C_L = 35 pF$	Room Full		7	32 34	ns
Break-Before-Make Time	t <sub>BBM</sub>		Room	1	12		
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega$	Room		3		рC
Off-Isolation <sup>d</sup>	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$	Room		- 58		٩D
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	11 <u>1</u> = 30 32, O <u>L</u> = 3 pr, r = 1 ΜΠΖ	Room		- 64		dB
N <sub>O</sub> , N <sub>C</sub> Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub> C <sub>NC(off)</sub>	V <sub>IN</sub> = 0 or V+, f = 1 MHz	Room		21		pF
Channel-On Capacitance <sup>d</sup>	C <sub>ON</sub>		Room		61		
Power Supply			1		1		ı
Power Supply Range	V+			1.8		5.5	V
Power Supply Current	I+	$V_{IN} = 0 \text{ or } V+$			0.01	1	μΑ



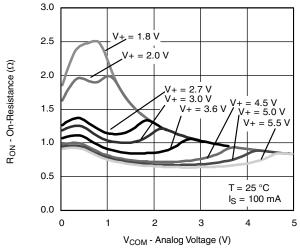
		Test Conditions Otherwise Unless Specified		<b>Limits</b> - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 5 V$ , $\pm 10 \%$ , $V_{IN} = 0.6 V$ or $1.8 V^e$	Temp.a	Min.b	Typ.c	Max.b	Uni
Analog Switch							
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC}, V_{COM}$		Full	0		V+	٧
On-Resistance	R <sub>ON</sub>	V. 45VV 05V/05V	Room Full		1	1.3 1.45	
R <sub>ON</sub> Match	$\Delta R_{ON}$	$V+ = 4.5 \text{ V}, V_{COM} = 0.5 \text{ V}/2.5 \text{ V},$ $I_{NO}, I_{NC} = 100 \text{ mA}$	Room			0.15	Ω
R <sub>ON</sub> Flatness	R <sub>ON</sub> Flatness	$I_{NO}$ , $I_{NC} = I_{OO} IIIA$	Room		0.3	0.4	
	I <sub>NO(off)</sub>		Room	- 2		2	
Switch Off Leakage Current	I <sub>NC(off)</sub>	V+ = 5.5 V,	Full	- 20	<u> </u>	20	
omon on zoamago oanom	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC}$ = 1 V/4.5 V, $V_{COM}$ = 4.5 V/1 V	Room Full	- 2 - 20		2 20	nA
Channel-On Leakage Current	I <sub>COM(on)</sub>	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V}/4.5 \text{ V}$	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.8			V
Input Low Voltage	V <sub>INL</sub>		Full			0.6	v
Input Capacitance	C <sub>in</sub>		Full		4		рF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0$ or $V+$	Full	1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>		Room Full		11	35 39	
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC}$ = 2.5 V, $R_L$ = 50 $\Omega$ , $C_L$ = 35 pF	Room Full		6	31 33	ns
Break-Before-Make Time	t <sub>BBM</sub>		Room	1	5		
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega$	Room		14		рC
Off-Isolation <sup>d</sup>	OIRR	$R_1 = 50 \Omega$ , $C_1 = 5 pF$ , $f = 1 MHz$	Room		- 58		40
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$11L = 30.32, O_L = 3 \text{ pr}, r = 1.00 \text{ m/s}$	Room		- 64		dE
N <sub>O</sub> , N <sub>C</sub> Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub> C <sub>NC(off)</sub>	V <sub>IN</sub> = 0 or V+, f = 1 MHz	Room		19		pF
Channel-On Capacitanced	C <sub>ON</sub>		Room		61		1
Power Supply							
Power Supply Range	V+	V <sub>IN</sub> = 0 or V+		1.8		5.5	٧
Power Supply Current	I+	VIN = O OI V+			0.01	1	μΑ

### Notes:

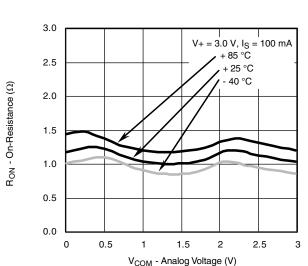
- a. Room = 25  $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

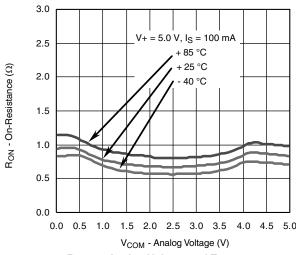
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



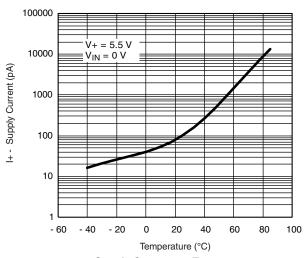
R<sub>ON</sub> vs. V<sub>COM</sub> and Supply Voltage



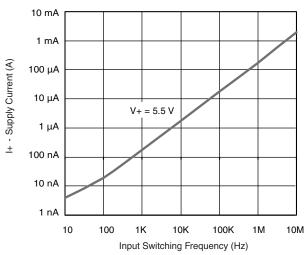
R<sub>ON</sub> vs. Analog Voltage and Temperature



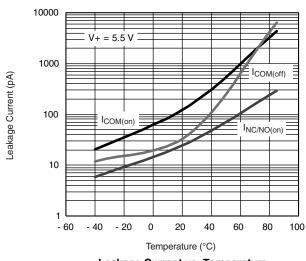
R<sub>ON</sub> vs. Analog Voltage and Temperature



Supply Current vs. Temperature



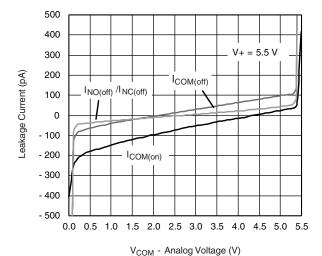
**Supply Current vs. Input Switching Frequency** 



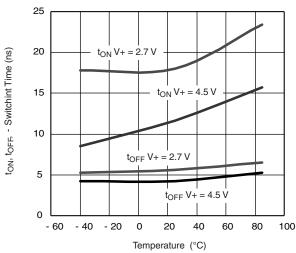
Leakage Current vs. Temperature



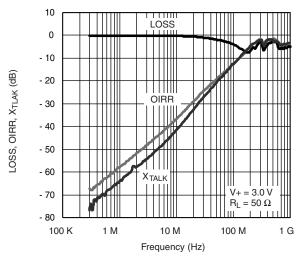
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



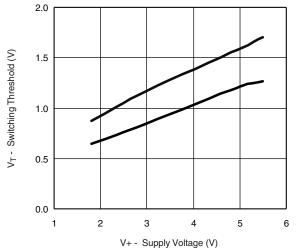
Leakage vs. Analog Voltage



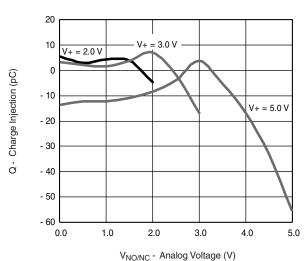
Switching Time vs. Temperature and Supply Voltage



Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



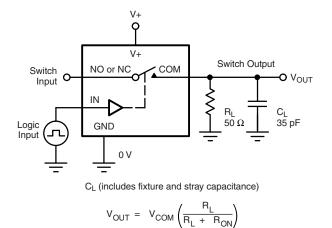
Switching Threshold vs. Supply Voltage

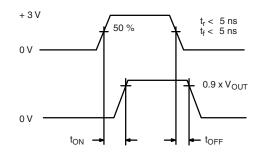


Charge Injection vs. Analog Voltage

### **TEST CIRCUITS**







Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

Logic

Input

Switch

Output

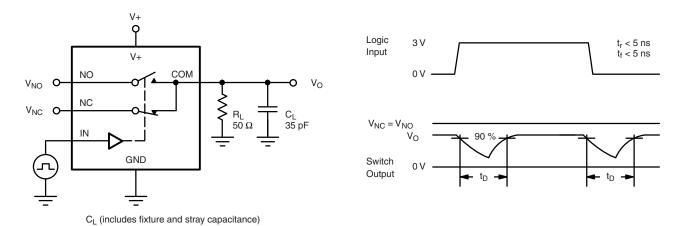


Figure 2. Break-Before-Make Interval

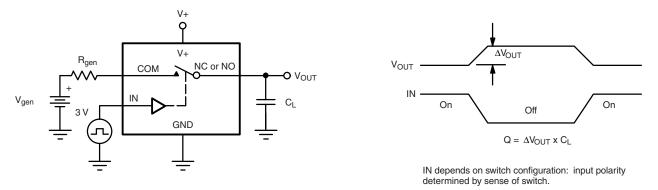


Figure 3. Charge Injection



# 10 nF COM 0 V, 2.4 V COM NC or NO Off Isolation = 20 log $V_{COM}$ **GND** Analyzer

Figure 4. Off-Isolation

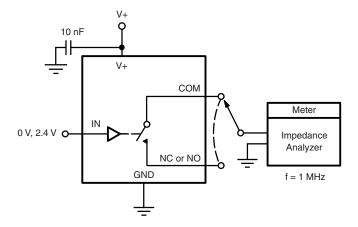
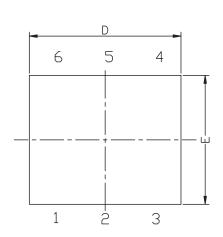
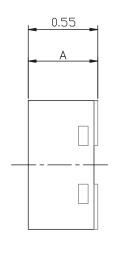


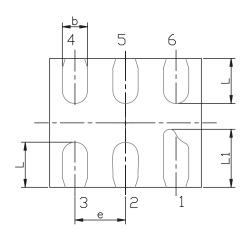
Figure 5. Channel Off/On Capacitance

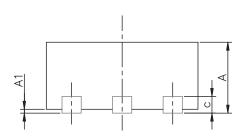
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?74454

# MINI QFN-6L CASE OUTLINE







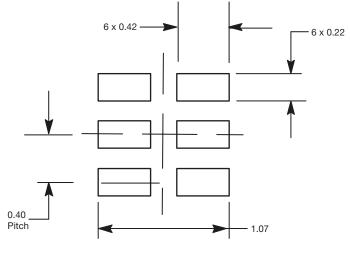


DIM	MILLIMETERS			INCHES		
DIIVI	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.
Α	0.50	0.55	0.60	0.0197	0.0217	0.0236
A1	0.00	-	0.05	0.000	ı	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.15 REF			0.006 REF		
D	1.15	1.20	1.25	0.045 0.047 0.049		
Е	0.95	1.00	1.05	0.037	0.039	0.041
е	0.40 BSC				0.016 BSC	
L	0.30	0.35	0.40	0.012	0.014	0.016
L1	0.40	0.45	0.50	0.016	0.018	0.020

ECN T-07039-Rev. A, 12-Feb-07 DWG: 5958



### **RECOMMENDED MINIMUM PADS FOR MINI QFN 6L**



Mounting Footprint Dimensions in mm



# **Legal Disclaimer Notice**

Vishay

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000

# AMEYA360 Components Supply Platform

# **Authorized Distribution Brand:**

























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